

### **Features**

- · Fast Switching
- · Improved dv/dt Capability
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **Maximum Ratings**

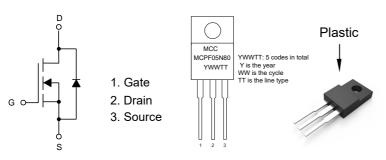
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 62.5°C/W Junction to Ambient
- Thermal Resistance: 5°C/W Junction to Case<sup>(Note 1)</sup>

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	800	V
Gate-Source Volltage	V <sub>GS</sub>	±30	V
Continuous Drain Current	I <sub>D</sub>	5	Α
Pulsed Drain Current (Note1)	I <sub>DM</sub>	20	Α
Single Pulse Avalanche Energy (Note 2)	E <sub>AS</sub>	151	mJ
Avalanche Current (Note1)	I <sub>AS</sub>	5.5	Α
Repetitive Avalanche Energy (Note1)	E <sub>AR</sub>	90	mJ
Total Power Dissipation	P <sub>D</sub>	25	W

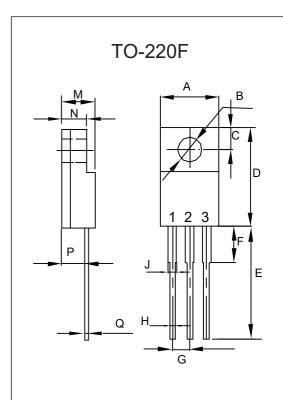
Note: 1.Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.

 $2.I_{AS}$ =3A,  $V_{DD}$ =50V,  $R_{G}$ =25  $\Omega$ , Starting  $T_{J}$ =25°C.

# **Internal Structure and Marking Code**



# N-CHANNEL MOSFET



	DIMENSIONS					
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.392	0.421	9.96	10.70		
В	0.138		3.50		Ф	
С	0.1	0.106		70	TYP.	
D	0.567	0.642	14.40	16.30		
E	0.520		13.20		TYP.	
F		0.177		4.50		
G	0.100		2.54		TYP.	
Н	0.020	0.035	0.50	0.90		
J	0.043	0.053	1.10	1.35		
М	0.169	0.201	4.30	5.10		
N		0.140		3.56		
Р	0.083	0.126	2.10	3.20		
Q	0.020	0.032	0.50	0.80		



# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

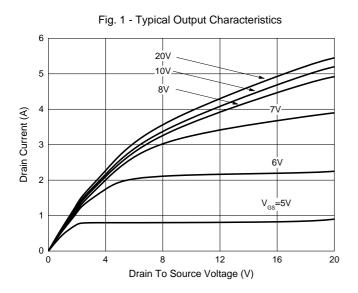
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics				1		
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	800			V
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±30V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =800V, V <sub>GS</sub> =0V		1		- µA
		V <sub>DS</sub> =640V, V <sub>GS</sub> =0V, T <sub>J</sub> =25°C	100		100	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	3		4	V
Drain-Source On-Resistance <sup>(Note 3)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =2.5A		2.3	2.8	Ω
Dynamic Characteristics(Note 4)					1	
Input Capacitance	C <sub>iss</sub>			667		
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V,f=1MHz		77		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			14		
Total Gate Charge	Qg			27		nC
Gate-Source Charge	$Q_{gs}$	V <sub>DD</sub> =640V,V <sub>GS</sub> =10V,I <sub>D</sub> =5A		3.5		
Gate-Drain Charge	$Q_{gd}$			13		
Turn-On Delay Time	t <sub>d(on)</sub>			37		
Turn-On Rise Time	t <sub>r</sub>			15		ns
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{DD} = 400V, I_{D} = 5A, R_{G} = 25\Omega$		144		
Turn-Off Fall Time	t <sub>f</sub>			41		
Drain-Source Body Diode Cha	racteristi	cs				
Continuous Body Diode Current	Is	T =25°C			5	^
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>C</sub> =25°C			20	Α
Body Diode Voltage	V <sub>SD</sub>	I <sub>SD</sub> =2.5A, V <sub>GS</sub> =0V			1.4	V
Reverse Recovery Time	t <sub>rr</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =5A,di <sub>F</sub> /dt=100A/μs		1099		ns
Reverse Recovery Charge	Q <sub>rr</sub>	v <sub>GS</sub> -υν, i <sub>S</sub> -υλ,ui <sub>F</sub> /ui- τυυλ/μS		3.2		μC

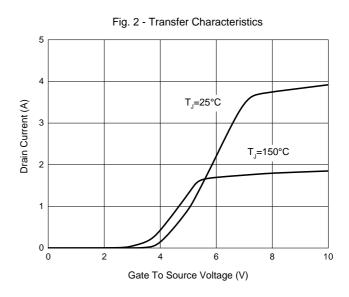
Note 3. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤ 1%.

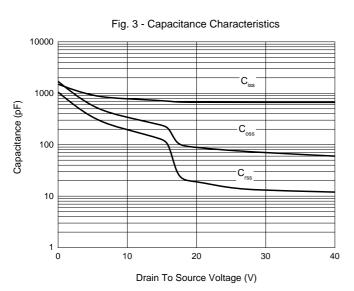
<sup>4.</sup> Guaranteed by Design, Not Subject to Production Testing.

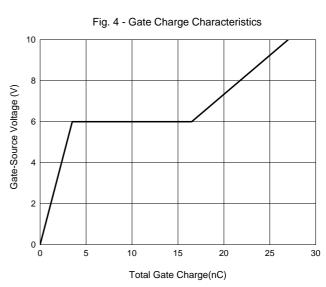


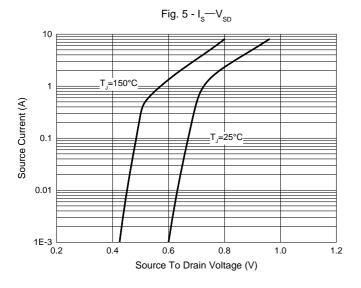
## **Curve Characteristics**

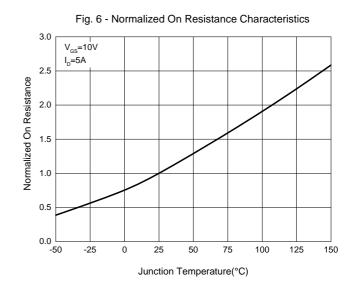














## **Ordering Information**

Device	Packing	
Part Number-BP	Bulk:50pcs/Tube,1Kpcs/Box,5Kpcs/Carton	

Note: Adding "-HF" Suffix For Halogen Free, eg. Part Number-BP-HF

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